

# DEC

SBP2020 THRU SBP20100

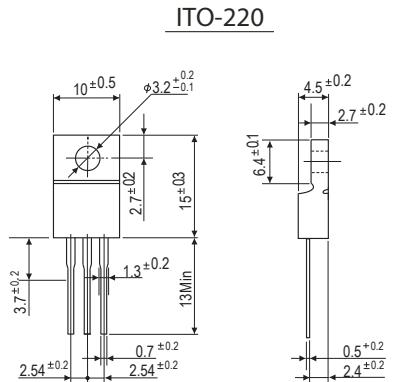
CURRENT 20.0Amperes  
VOLTAGE 20 to 100 Volts

## Features

- Plastic Package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction, majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss, high efficiency
- High current capability, Low forward voltage drop
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- Dual rectifier construction
- High temperature soldering guaranteed:  
250 °C/10 seconds, 0.25" (6.35mm) from case

## Mechanical Data

- Case : JEDEC TO-220 molded plastic body
- Terminals : Lead solderable per MIL-STD-750, Method 2026
- Polarity : As marked. No suffix indicates Common Cathode, suffix "A" indicates Common Anode
- Mounting Position : Any
- Weight : 0.08ounce, 2.24 grams



Dimensions in inches and (millimeters)

## Maximum Ratings and Electrical Characteristics

(Ratings at 25 °C ambient temperature unless otherwise specified, single phase, half wave, resistive or inductive load. For capacitive load, derate by 20%)

	Symbols	SBP 2020	SBP 2030	SBP 2040	SBP 2050	SBP 2060	SBP 2080	SBP 20100	Units
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	20	30	40	50	60	80	100	Volts
Maximum RMS voltage	V <sub>RMS</sub>	14	21	28	35	42	56	70	Volts
Maximum DC blocking voltage	V <sub>DC</sub>	20	30	40	50	60	80	100	Volts
Maximum average forward rectified current at T <sub>c</sub> =105 °C	I(AV)				20.0				Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I <sub>FSM</sub>			150.0		125.0			Amps
Maximum instantaneous forward voltage at 10A (Note 1)	V <sub>F</sub>		0.60		0.75		0.90		Volts
Maximum instantaneous reverse current at rated DC blocking voltage (Note1)	I <sub>R</sub>			1.0					mA
				100.0					
Typical thermal resistance (Note 2)	R <sub>θJC</sub>			3.5					°C/W
Operating junction temperature range	T <sub>J</sub>			-50 to +125					°C
Storage temperature range	T <sub>STG</sub>			-65 to +150					°C

### Notes:

- (1) Pulse test: 300µS pulse width, 1% duty cycle
- (2) Thermal resistance from junction to case

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## RATINGS AND CHARACTERISTIC CURVES SBP2020 THRU SBP20100

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

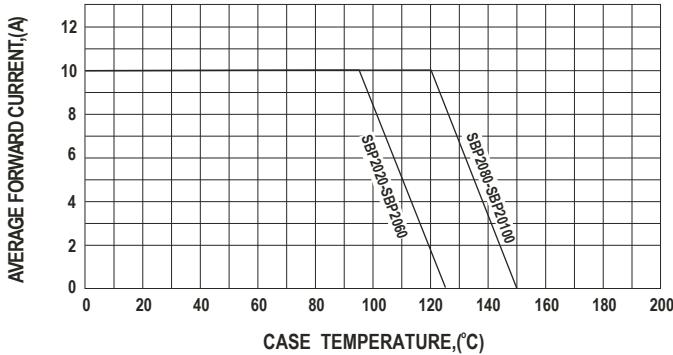


FIG.3-MAXIMUM NON-REPETITIVE FORWARDSURGE CURRENT

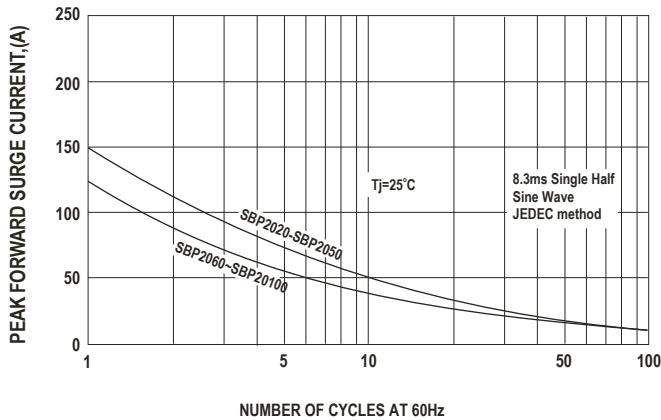


FIG.4-TYPICAL JUNCTION CAPACITANCE

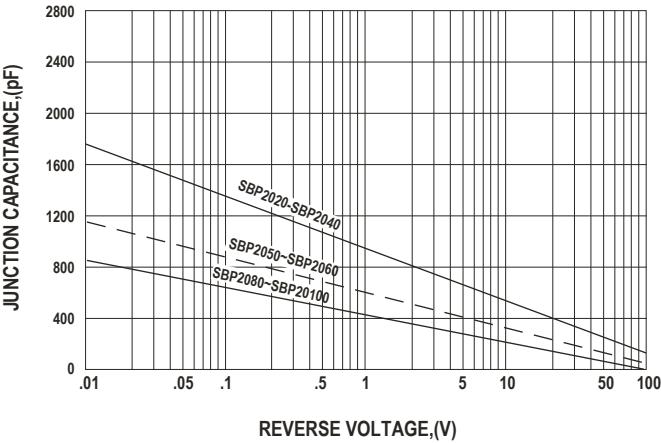


FIG.2-TYPICAL FORWARD CHARACTERISTICS

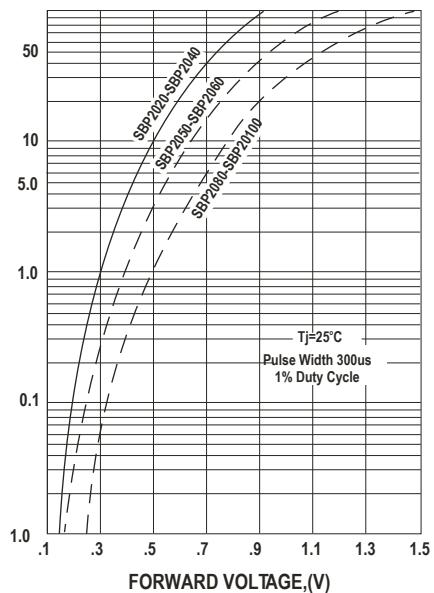


FIG.5 - TYPICAL REVERSE CHARACTERISTICS

